## NSN 5962-01-611-4206

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View Online at https://aerobasegroup.com/nsn/5962-01-611-4206 **Overall Length:** Between 0.642 inches and 0.658 inches **Overall Height:** Between 0.256 inches and 0.286 inches Overall Width: Between 0.542 inches and 0.558 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0 to 125.0 degrees celsius Storage Tempurature Range: -65.0 to 150.0 degrees celsius **End Application:** An/alr 56 arw **Inclosure Material:** Ceramic **Inclosure Configuration:** Pin grid array **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Current Rating Per Characteristic:** 80.0 milliamperes supply **Product Name:** Microcircuit, digital, cmos, eeprom with software triggered Voltage Rating And Type Per Characteristic: 4.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 120.00 nanoseconds access **Memory Device Type: Eeprom Hybrid Technology Type:** Monolithic **Memory Capacity:** 32kx8 **Terminal Type And Quantity:** 28 pin Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

Yes - demil/mli

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